

## 2010 Technical Session Authors Index

**Note:** This list is the preliminary Author Index as of Jan. 12, 2010, and does not include education course instructors. For the most up-to-date author's listing, see the program guide distributed on site in Las Vegas.

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 Wood, R. 3C  
 Woodfall, M. 2D  
 Wooton, D. 1E, 2A  
 Wopelka, T. 5I  
 Wurzbach, R. 1E, 2E

### X

Xiangjun, Z. 6D, 7B  
 Xiaohao, Z. 6D, 7B  
 Xu, H. 8E

### Y

Yablon, D. 5C, 5D  
 Yamaguchi, E. 3B  
 Yang, S. 7F, 2B  
 Yang, Y. 8A  
 Yaung, P. 4F Yongjian, L. 4G  
 Yoon, E. 2B  
 Yoshihara, Y. 7H  
 Young, L. 2F  
 Yuan, T. 5E  
 Yun, H. 2E

### Z

Zaccheddu, M. 3B  
 Zarbu, M. 6C  
 Zaretsky, E. 6I  
 Zdrodowski, R. 3C  
 Zhang, B. 6C  
 Zhang, H. 2B  
 Zhang, J. 3B, 6C, 7F  
 Zhang, R. 5I  
 Zhang, W. 7C, 8A  
 Zhao, H. 7G  
 Zhao, X. 7C  
 Zhao, Y. 4E  
 Zhou, J. 4B, 5F  
 Zhou, K. 6I  
 Zhu, D. 2C, 5B, 6B  
 Zhu, H. 2G  
 Zou, M. 1B  
 Zou, Q. 5I  
 Zulkepli, N. 4I



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